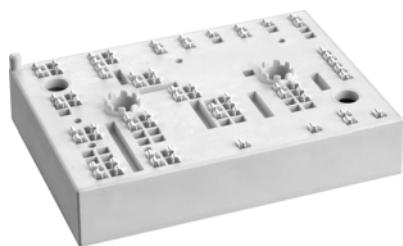


# SKiiP 35ACC12T7V1



MiniSKiiP® 3

## Twelvepack

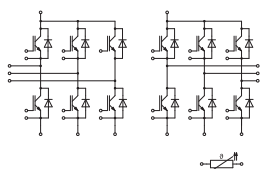
### SKiiP 35ACC12T7V1

#### Features\*

- 1200V Generation 7 IGBTs (T7)
- Robust and soft switching freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognized: File no. E63532

#### Remarks

- Max. case temperature limited to  $T_C = T_S = 125^\circ\text{C}$
- Product reliability results valid for  $T_j \leq 150^\circ\text{C}$  (recommended  $T_{j,op} = -40 \dots +150^\circ\text{C}$ )
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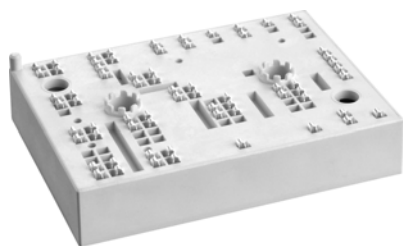


ACC

Absolute Maximum Ratings				
Symbol	Conditions		Values	Unit
Inverter - IGBT				
V <sub>CES</sub>	T <sub>j</sub> = 25 °C		1200	V
I <sub>C</sub>	λ <sub>paste</sub> =0.8 W/(mK) T <sub>j</sub> = 175 °C	T <sub>s</sub> = 70 °C	60	A
		T <sub>s</sub> = 100 °C	48	A
I <sub>C</sub>	λ <sub>paste</sub> =2.5 W/(mK) T <sub>j</sub> = 175 °C	T <sub>s</sub> = 70 °C	68	A
		T <sub>s</sub> = 100 °C	55	A
I <sub>Cnom</sub>			50	A
I <sub>CRM</sub>			100	A
V <sub>GES</sub>			-20 ... 20	V
t <sub>psc</sub>	V <sub>CC</sub> = 800 V V <sub>GE</sub> ≤ 15 V V <sub>CES</sub> ≤ 1200 V	T <sub>j</sub> = 175 °C	7	μs
T <sub>j</sub>			-40 ... 175	°C
Inverse - Diode				
V <sub>RRM</sub>	T <sub>j</sub> = 25 °C		1200	V
I <sub>F</sub>	λ <sub>paste</sub> =0.8 W/(mK) T <sub>j</sub> = 175 °C	T <sub>s</sub> = 70 °C	48	A
		T <sub>s</sub> = 100 °C	39	A
I <sub>F</sub>	λ <sub>paste</sub> =2.5 W/(mK) T <sub>j</sub> = 175 °C	T <sub>s</sub> = 70 °C	54	A
		T <sub>s</sub> = 100 °C	44	A
I <sub>FRM</sub>			100	A
I <sub>FSM</sub>	t <sub>p</sub> = 10 ms, sin 180°, T <sub>j</sub> = 150 °C		270	A
T <sub>j</sub>			-40 ... 175	°C
Module				
I <sub>t(RMS)</sub>	T <sub>terminal</sub> = 80 °C, 20 A per spring		40	A
T <sub>stg</sub>	module without TIM		-40 ... 125	°C
V <sub>isol</sub>	AC sinus 50 Hz, t = 1 min		2500	V

Characteristics						
Symbol	Conditions		min.	typ.	max.	Unit
Inverter - IGBT						
V <sub>CE(sat)</sub>	I <sub>C</sub> = 50 A	T <sub>j</sub> = 25 °C		1.55	1.70	V
	V <sub>GE</sub> = 15 V chiplevel	T <sub>j</sub> = 150 °C		1.73	1.88	V
		T <sub>j</sub> = 175 °C		1.77	1.92	V
V <sub>CE0</sub>	chiplevel	T <sub>j</sub> = 25 °C		1.00	1.05	V
		T <sub>j</sub> = 150 °C		0.80	0.85	V
		T <sub>j</sub> = 175 °C		0.75	0.80	V
r <sub>CE</sub>	V <sub>GE</sub> = 15 V chiplevel	T <sub>j</sub> = 25 °C		11	13	mΩ
		T <sub>j</sub> = 150 °C		19	21	mΩ
		T <sub>j</sub> = 175 °C		20	22	mΩ
V <sub>GE(th)</sub>	V <sub>GE</sub> = V <sub>CE</sub> , I <sub>C</sub> = 1.27 mA		5.15	5.8	6.45	V
I <sub>CES</sub>	V <sub>GE</sub> = 0 V, V <sub>CE</sub> = 1200 V, T <sub>j</sub> = 25 °C				1	mA
C <sub>ies</sub>	V <sub>CE</sub> = 25 V V <sub>GE</sub> = 0 V	f = 1 MHz		10.00		nF
C <sub>oes</sub>		f = 1 MHz		0.13		nF
C <sub>res</sub>		f = 1 MHz		0.04		nF
Q <sub>G</sub>	V <sub>GE</sub> = - 8V ... + 15 V			700		nC
R <sub>Gint</sub>	T <sub>j</sub> = 25 °C			0		Ω

# SKiiP 35ACC12T7V1



MiniSKiiP® 3

## Twelvepack

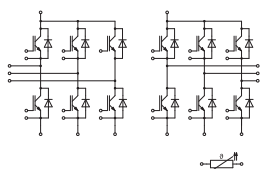
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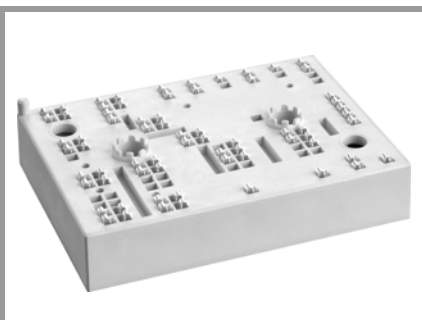


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Characteristics					
Symbol	Conditions		min.	typ.	max. Unit
<b>Inverter - IGBT</b>					
$t_{d(on)}$	$V_{CC} = 600\text{ V}$ $I_C = 50\text{ A}$ $R_{G on} = 6.4\ \Omega$ $R_{G off} = 6.4\ \Omega$ $V_{GE} = +15/-15\text{ V}$	$T_j = 25^\circ\text{C}$		32	ns
		$T_j = 150^\circ\text{C}$		36	ns
		$T_j = 175^\circ\text{C}$		36	ns
$t_r$		$T_j = 25^\circ\text{C}$		37	ns
		$T_j = 150^\circ\text{C}$		42	ns
		$T_j = 175^\circ\text{C}$		45	ns
$E_{on}$	$R_{G on} = 6.4\ \Omega$ $R_{G off} = 6.4\ \Omega$ $V_{GE} = +15/-15\text{ V}$	$T_j = 25^\circ\text{C}$		4	mJ
		$T_j = 150^\circ\text{C}$		5.7	mJ
		$T_j = 175^\circ\text{C}$		6	mJ
$t_{d(off)}$		$T_j = 25^\circ\text{C}$		250	ns
		$T_j = 150^\circ\text{C}$		340	ns
		$T_j = 175^\circ\text{C}$		365	ns
$t_f$	@ $T_j = 150^\circ\text{C}$ : $di/dt_{on} = 1270\text{ A}/\mu\text{s}$ $di/dt_{off} = 530\text{ A}/\mu\text{s}$ $dv/dt = 3620\text{ V}/\mu\text{s}$	$T_j = 25^\circ\text{C}$		51	ns
		$T_j = 150^\circ\text{C}$		79	ns
		$T_j = 175^\circ\text{C}$		94	ns
$E_{off}$		$T_j = 25^\circ\text{C}$		3.3	mJ
		$T_j = 150^\circ\text{C}$		5.5	mJ
		$T_j = 175^\circ\text{C}$		6	mJ
$R_{th(j-s)}$	per IGBT, $\lambda_{paste} = 0.8\text{ W}/(\text{mK})$			0.83	K/W
$R_{th(j-s)}$	per IGBT, $\lambda_{paste} = 2.5\text{ W}/(\text{mK})$			0.67	K/W

Characteristics					
Symbol	Conditions		min.	typ.	max. Unit
<b>Inverse - Diode</b>					
$V_F = V_{EC}$	$I_F = 50\text{ A}$ $V_{GE} = 0\text{ V}$ chipelevel	$T_j = 25^\circ\text{C}$		2.22	2.54 V
		$T_j = 150^\circ\text{C}$		2.18	2.50 V
		$T_j = 175^\circ\text{C}$		2.03	2.34 V
$V_{F0}$	chipelevel	$T_j = 25^\circ\text{C}$		1.30	1.50 V
		$T_j = 150^\circ\text{C}$		0.90	1.10 V
		$T_j = 175^\circ\text{C}$		0.82	0.98 V
$r_F$	chipelevel	$T_j = 25^\circ\text{C}$		18	21 mΩ
		$T_j = 150^\circ\text{C}$		26	28 mΩ
		$T_j = 175^\circ\text{C}$		24	27 mΩ
$I_{RRM}$	$I_F = 50\text{ A}$ $V_{GE} = +15/-15\text{ V}$ $V_{CC} = 600\text{ V}$	$T_j = 25^\circ\text{C}$		32	A
		$T_j = 150^\circ\text{C}$		42	A
		$T_j = 175^\circ\text{C}$		50	A
$Q_{rr}$		$T_j = 25^\circ\text{C}$		2.8	μC
		$T_j = 150^\circ\text{C}$		7.6	μC
		$T_j = 175^\circ\text{C}$		8.2	μC
$E_{rr}$	@ $T_j = 150^\circ\text{C}$ : $di/dt_{off} = 1270\text{ A}/\mu\text{s}$	$T_j = 25^\circ\text{C}$		0.9	mJ
		$T_j = 150^\circ\text{C}$		3	mJ
		$T_j = 175^\circ\text{C}$		4	mJ
$R_{th(j-s)}$	per Diode, $\lambda_{paste} = 0.8\text{ W}/(\text{mK})$			0.96	K/W
$R_{th(j-s)}$	per Diode, $\lambda_{paste} = 2.5\text{ W}/(\text{mK})$			0.8	K/W
<b>Module</b>					
$L_{CE}$				-	nH
$M_s$	to heat sink		2		2.5 Nm
w				82	g

# SKiiP 35ACC12T7V1



MiniSKiiP® 3

## Twelvepack

### SKiiP 35ACC12T7V1

#### Features\*

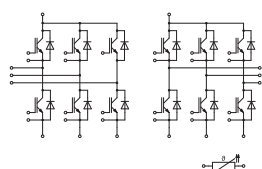
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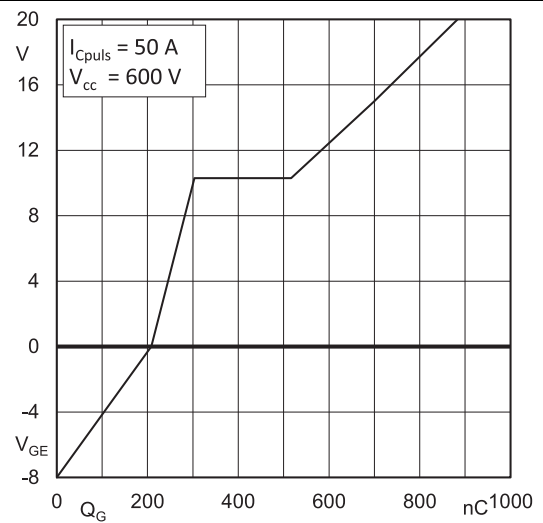
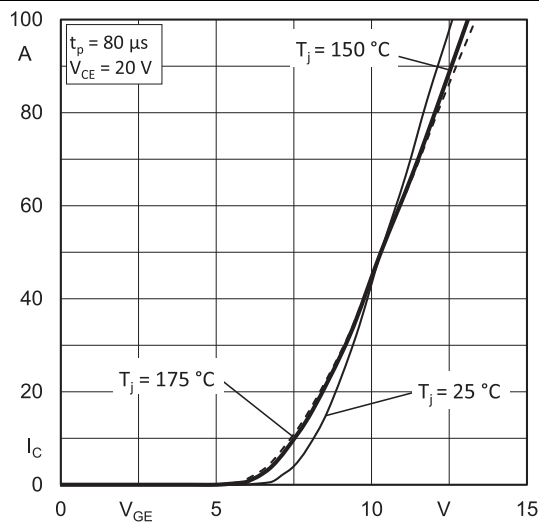
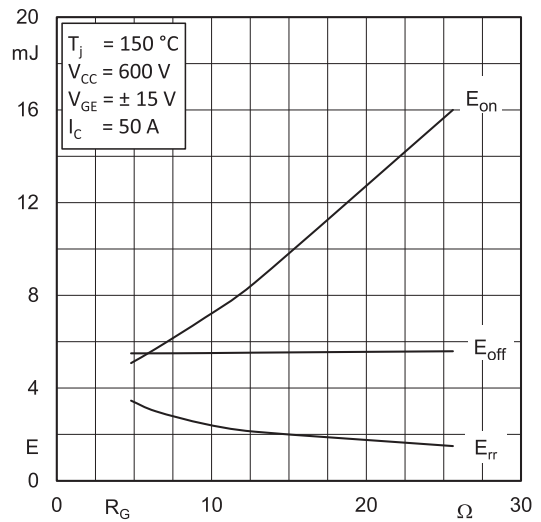
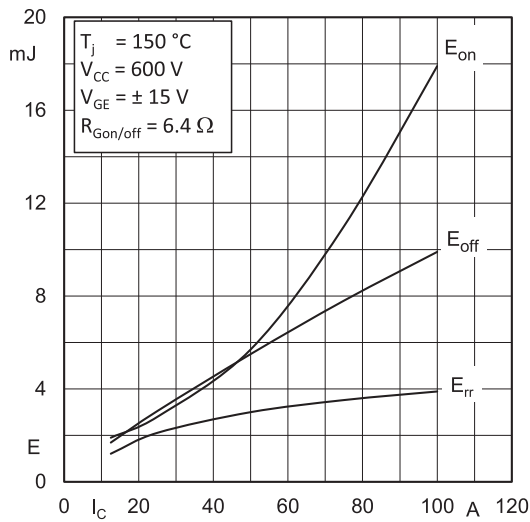
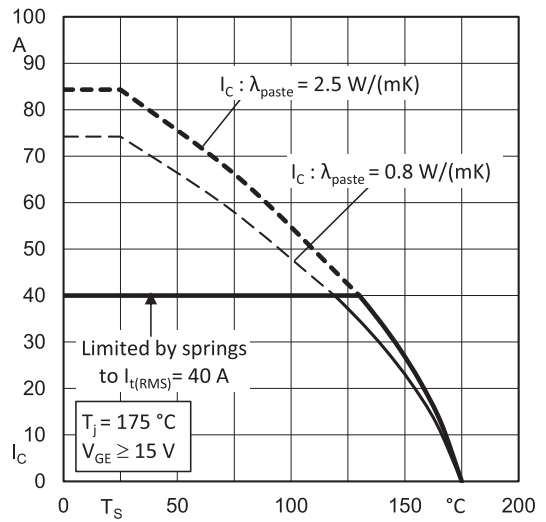
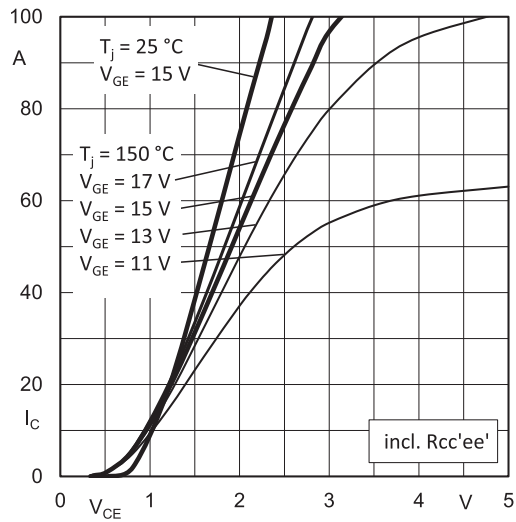
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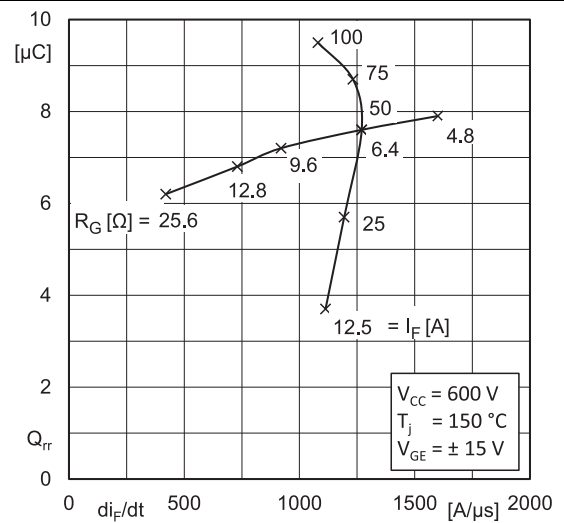
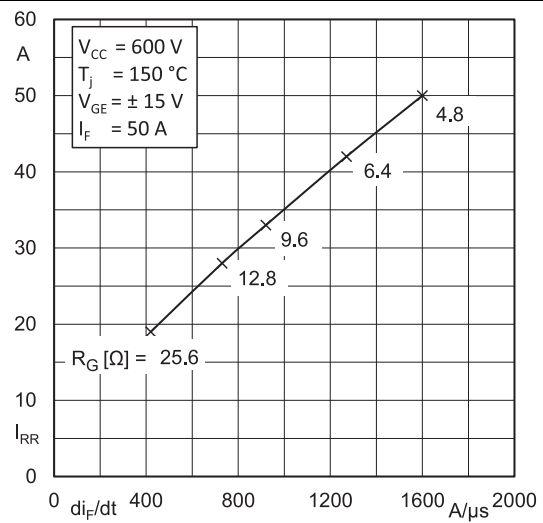
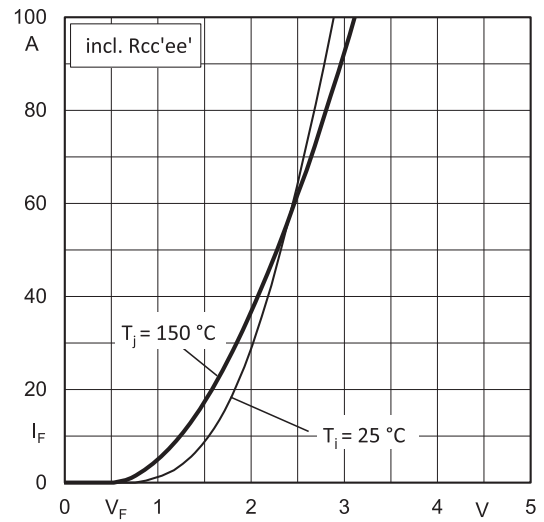
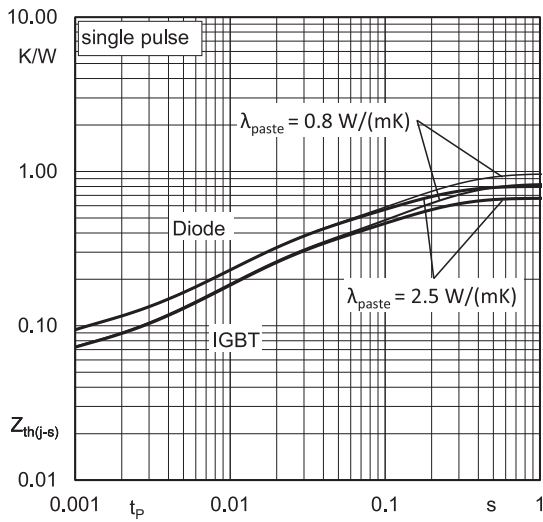
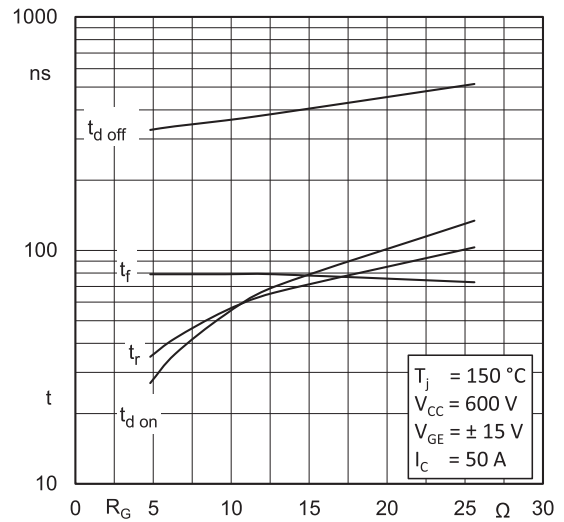
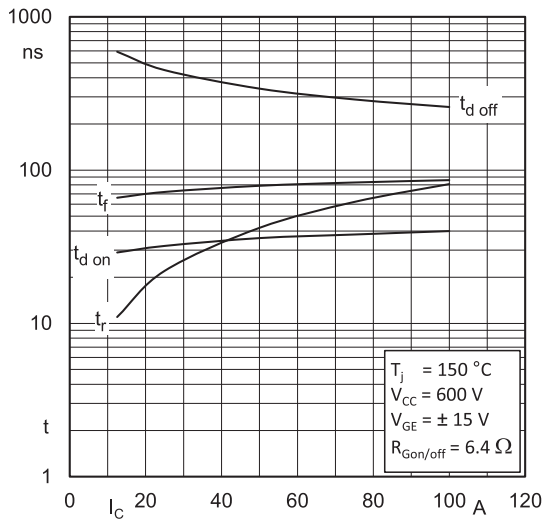
Characteristics					
Symbol	Conditions	min.	typ.	max.	Unit
<b>Temperature Sensor</b>					
$R_{100}$	$T_f = 100\text{ °C}$ ( $R_{25} = 1000\Omega$ )		$1670 \pm 3\%$		$\Omega$
$R_{(T)}$	$R_{(T)} = 1000\Omega [1 + A(T - 25\text{ °C}) + B(T - 25\text{ °C})^2]$ $A = 7.635 \cdot 10^{-3}\text{ °C}^{-1}$ , $B = 1.731 \cdot 10^{-5}\text{ °C}^{-2}$				

Creepage distance (spring to spring) between temperature sensor and DC- = 0.8mm (CTI 600)



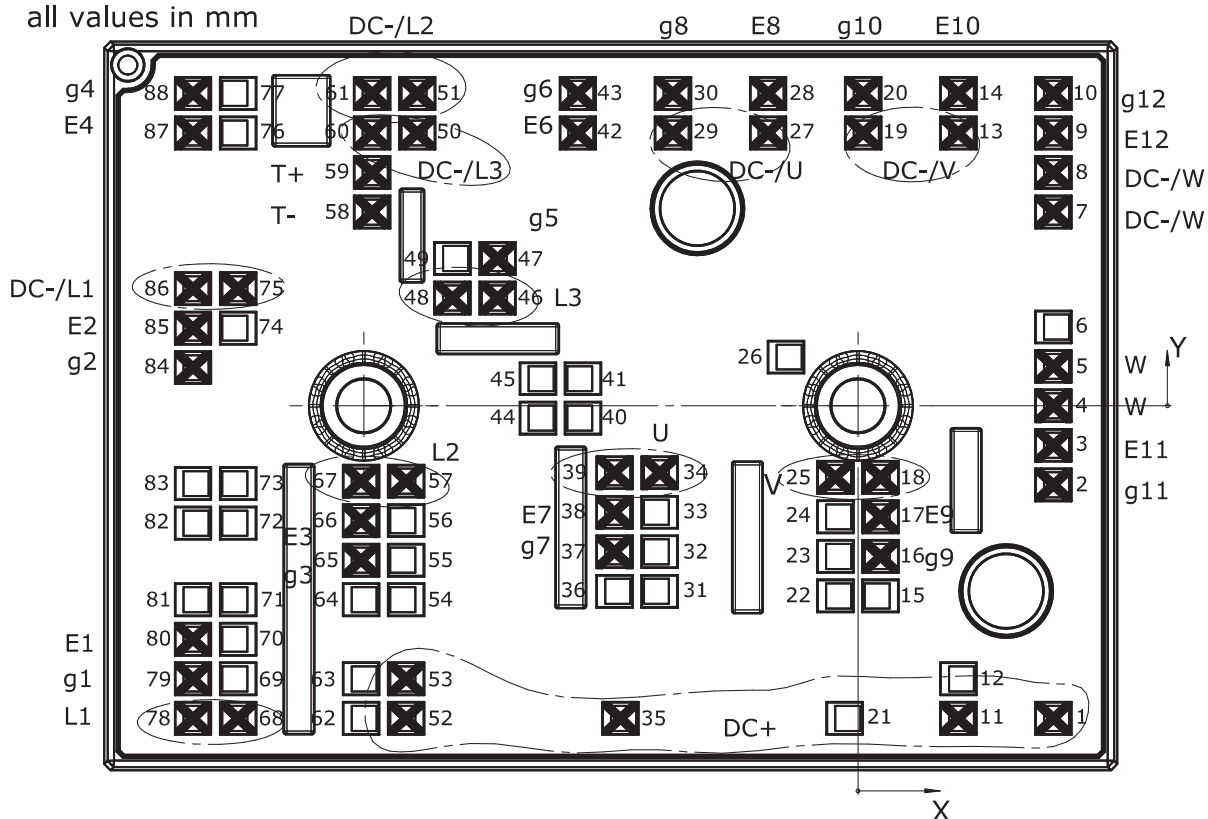
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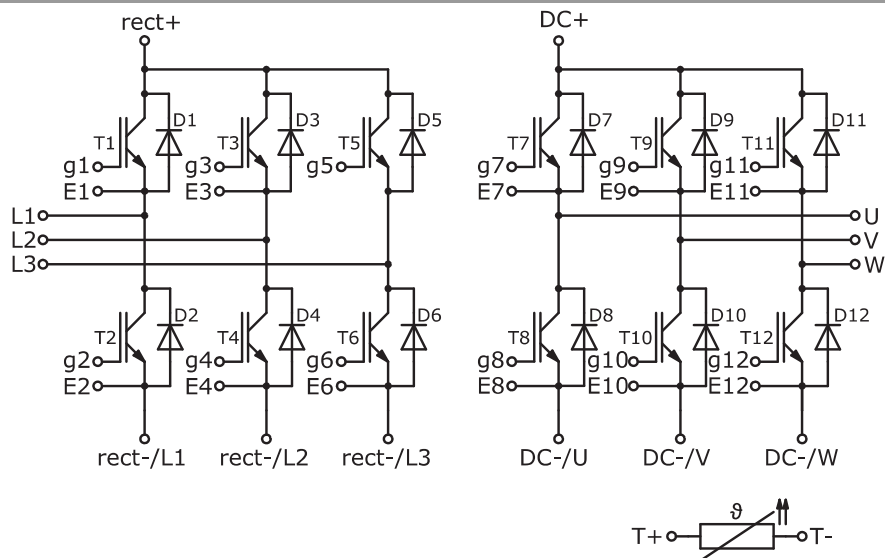


Pin out											
Pin	X	Y	Function	Pin	X	Y	Function	Pin	X	Y	Function
1	15,83	-25,30	DC+	31	-16,05	-15,02		61	-39,33	25,30	DC-/L2
2	15,83	-6,40	g11	32	-16,05	-11,82		62	-40,23	-25,30	
3	15,83	-3,20	E11	33	-16,05	-8,62		63	-40,23	-22,10	
4	15,83	0	W	34	-16,05	-5,42	U	64	-40,23	-15,70	
5	15,83	3,20	W	35	-19,23	-25,30	DC+	65	-40,23	-12,50	g3
6	15,83	6,40		36	-19,70	-15,02		66	-40,23	-9,30	E3
7	15,83	15,70	DC-/W	37	-19,70	-11,82	g7	67	-40,23	-6,10	L2
8	15,83	18,90	DC-/W	38	-19,70	-8,62	E7	68	-50,18	-25,30	L1
9	15,83	22,10	E12	39	-19,70	-5,42	U	69	-50,18	-22,10	
10	15,83	25,30	g12	40	-22,26	-1,00		70	-50,18	-18,90	
11	8,13	-25,30	DC+	41	-22,26	2,20		71	-50,18	-15,70	
12	8,13	-22,10		42	-22,68	22,10	E6	72	-50,18	-9,50	
13	8,13	22,10	DC-/V	43	-22,68	25,30	g6	73	-50,18	-6,30	
14	8,13	25,30	E10	44	-25,91	-1,00		74	-50,18	6,30	
15	1,83	-15,39		45	-25,91	2,20		75	-50,18	9,50	DC-/L1
16	1,83	-12,19	g9	46	-29,18	8,74	L3	76	-50,18	22,10	
17	1,83	-8,99	E9	47	-29,18	11,94	g5	77	-50,18	25,30	
18	1,83	-5,79	V	48	-32,83	8,74	L3	78	-53,83	-25,30	L1
19	0,43	22,10	DC-/V	49	-32,83	11,94		79	-53,83	-22,10	g1
20	0,43	25,30	g10	50	-35,68	22,10	DC-/L3	80	-53,83	-18,90	E1
21	-1,08	-25,30		51	-35,68	25,30	DC-/L2	81	-53,83	-15,70	
22	-1,83	-15,39		52	-36,58	-25,30	DC+	82	-53,83	-9,50	
23	-1,83	-12,19		53	-36,58	-22,10	DC+	83	-53,83	-6,30	
24	-1,83	-8,99		54	-36,58	-15,70		84	-53,83	3,10	g2
25	-1,83	-5,79	V	55	-36,58	-12,50		85	-53,83	6,30	E2
26	-5,83	3,95		56	-36,58	-9,30		86	-53,83	9,50	DC-/L1
27	-7,28	22,10	DC-/U	57	-36,58	-6,10	L2	87	-53,83	22,10	E4
28	-7,28	25,30	E8	58	-39,33	15,70	T-	88	-53,83	25,30	g4
29	-14,98	22,10	DC-/U	59	-39,33	18,90	T+				
30	-14,98	25,30	g8	60	-39,33	22,10	DC-/L3				

all values in mm



Pinout



Pinout

This is an electrostatic discharge sensitive device (ESDS) due to international standard IEC 61340.

## \*IMPORTANT INFORMATION AND WARNINGS

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